

Soft Matter

Accepted Manuscript



This is an *Accepted Manuscript*, which has been through the Royal Society of Chemistry peer review process and has been accepted for publication.

Accepted Manuscripts are published online shortly after acceptance, before technical editing, formatting and proof reading. Using this free service, authors can make their results available to the community, in citable form, before we publish the edited article. We will replace this *Accepted Manuscript* with the edited and formatted *Advance Article* as soon as it is available.

You can find more information about *Accepted Manuscripts* in the [Information for Authors](#).

Please note that technical editing may introduce minor changes to the text and/or graphics, which may alter content. The journal's standard [Terms & Conditions](#) and the [Ethical guidelines](#) still apply. In no event shall the Royal Society of Chemistry be held responsible for any errors or omissions in this *Accepted Manuscript* or any consequences arising from the use of any information it contains.

Magnetic control of flexoelectric domains in a nematic fluid[†]

Péter Salamon,^{*a} Nándor Éber,^a Ágnes Buka^a, Tanya Ostapenko^b, Sarah Dölle^b, and Ralf Stannarius^b

Received Xth XXXXXXXXXXXX 20XX, Accepted Xth XXXXXXXXXXXX 20XX

First published on the web Xth XXXXXXXXXXXX 200X

DOI: 10.1039/b000000x

The formation of flexoelectric stripe patterns (flexodomains) was studied under the influence of external electric and magnetic fields in a nematic liquid crystal. The critical voltage and wave vector of flexodomains were investigated in different geometries by both experiments and simulations. It is demonstrated that altering the orientation of the magnetic field with respect to the director, the critical voltage and wave number behave substantially differently. In the geometry of the twist Freedericksz transition, a non-monotonic behavior as a function of the magnetic field was found.

1 Introduction

Nematic liquid crystals are anisotropic fluids with uniaxial orientational order, but without discrete translational symmetry¹. They typically consist of elongated molecules that fluctuate around the local axis of symmetry described by a unit vector called the director (\mathbf{n}). The practical importance of nematic liquid crystals originates from their controllability by external electric and magnetic fields. In display applications, an electric field is used to switch the director, which can adjust the optical properties of a device².

The majority of display modes utilizes the Freedericksz transition: an external field-induced director reorientation, where the driving torques originate from the anisotropies of the dielectric constant (ϵ_a) and/or the diamagnetic susceptibility (χ_a)³. The value of ϵ_a (χ_a) is given by the difference of the dielectric constants (diamagnetic susceptibilities) measured in an electric field (magnetic field) parallel to and perpendicular to the director: $\epsilon_a = \epsilon_{\parallel} - \epsilon_{\perp}$ ($\chi_a = \chi_{\parallel} - \chi_{\perp}$). If $\epsilon_a > 0$ ($\chi_a > 0$), the director tends to be parallel to the applied electric (magnetic) field. Otherwise, the perpendicular configuration is more favorable. If a destabilizing field is precisely perpendicular to (or, for negative anisotropies, parallel to) the initial homogeneous director, the torques vanish and the reorientation starts only above a well-defined threshold field, due to small fluctuations.

In the electric Freedericksz transition, the dielectric interaction dominates, which is described by a free energy contribution quadratic in the magnitude of the electric field. In addition, the director may be coupled linearly with the elec-

tric field via the flexoelectric interaction^{4,5}. Flexoelectricity means that a polarization is induced by a splay or bend deformation of the director \mathbf{n} , defined as:

$$\mathbf{P}_{\text{fl}} = e_1 \mathbf{n}(\nabla \mathbf{n}) + e_3 (\nabla \times \mathbf{n}) \times \mathbf{n}, \quad (1)$$

where e_1 and e_3 are the splay and bend flexoelectric coefficients, respectively. The usual order of magnitude for e_1 and e_3 is pC/m, though giant (a few nC/m) values^{6,7} were also reported for e_3 of bent-core^{8–14} liquid crystals.

Nematics are excellent materials to study spontaneous pattern formation¹⁵, as nonlinearities in their physical properties provide a rich source of patterns, and external electromagnetic fields can serve as control parameters. For example, applying an electric field on a planar nematic layer can induce instabilities that result in different types of periodic director deformations.

In the present paper, we focus on a particular pattern, the so-called flexodomains (FDs), which represent an equilibrium director modulation caused by flexoelectricity^{16,17}. They appear as stripes parallel to the initial director \mathbf{n}_0 . The first theoretical model of FDs only considered the one elastic constant approximation¹⁶, but this already gave a good qualitative explanation of the phenomenon. Recently, a detailed theoretical description of FDs was developed^{18,19} that also accounted for unequal elastic constants and for the dynamic behavior of FDs exposed to sinusoidal voltage excitation¹⁸. Furthermore, it recognized the similarity between FDs and splay-twist domains of the periodic Freedericksz transition; the latter were observed in polymeric liquid crystals with large elastic anisotropy²⁰.

Recently, nonlinear field effects and defect dynamics were also investigated in flexodomains^{21,22} in a bent-core compound. Moreover, flexoelectric patterns were studied in special geometries, such as twisted nematic (TN) cells using rod-like

^a Institute for Solid State Physics and Optics, Wigner Research Centre for Physics, Hungarian Academy of Sciences, Budapest, Hungary

* E-mail: salamon.peter@wigner.mta.hu

^b Institute for Experimental Physics, Otto-von-Guericke Universität, Universitätsplatz 2, 39106 Magdeburg, Germany

compounds²³ and lately in bent-core nematic liquid crystals^{24,25}, where the voltage-polarity dependent orientation of the flexoelectric stripes indicated that those domains are localized near the electrodes due to an electric field gradient.

In this work, we study how an additional magnetic field affects the formation of flexodomains. In order to give a complete answer, we performed experiments and developed a theoretical description, including magnetic fields applied in different geometries. Since flexodomains appear as an electric field-induced equilibrium deformation, similar to the electric Freedericksz transition, it is a plausible idea to compare the characteristics of these two phenomena in the presence of applied magnetic fields. In the present paper, we also make this comparison using our findings on flexodomains in magnetic fields.

The practical importance of flexodomains lies in the fact that they offer a method to determine the flexoelectric parameter $e^* = |e_1 - e_3|$ that is otherwise only measurable by complicated or unreliable techniques. Classical measuring methods deduce flexoelectric parameters from the electro-optical response and require precise knowledge of the voltage applied on the liquid crystal⁵. Since the optical response originating from flexoelectricity is linearly coupled to the electric field, very low frequency or DC voltages should be applied in order to avoid the damping of the optical response by the viscosities of the liquid crystal. Unfortunately, under such conditions, an internal voltage attenuation at the aligning layers and ionic effects^{26–36} are unavoidable, resulting in erroneous voltage data. The main advantage of using FDs for determining e^* is that the flexoelectric parameter can be calculated solely from the critical wave number, regardless of the value of the critical voltage. Indeed, analysis of FDs using the sophisticated theoretical description¹⁸ has been successfully employed recently for measuring e^* in a rod-like nematic³⁷. It should be noted, however, that the applicability of this method is limited; only a few compounds exhibit flexodomains, as the flexoelectric instability requires a special combination of material parameters¹⁸. If the dielectric torque acting on the director is too large, the flexoelectric pattern formation is suppressed. Thus, an important requirement is a small $|\epsilon_a|$. We will show that the limits of applicability might be extended if a magnetic field is also applied.

2 Experimental conditions

Our experimental investigations were performed on a typical rod-like nematic liquid crystal 4-n-octyloxyphenyl 4-n-methoxybenzoate (10O8*). The chemical structure of 10O8 can be seen in Fig. 1.

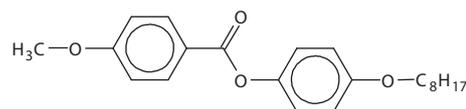


Fig. 1 The chemical structure of the rod-like molecule 4-n-octyloxyphenyl 4-n-methoxybenzoate (10O8).

10O8 only shows the nematic mesophase below a clearing point (T_{NI}) of 76.7 °C. In heating, it melts from the crystalline phase to nematic at 63.5 °C; the nematic phase can be supercooled down to 53 °C.

Several material parameters of 10O8 were determined as a function of temperature in a previous work³⁷. Here, we will use the bulk elastic constants (K_{11}, K_{22}, K_{33}), the dielectric, and the diamagnetic susceptibility anisotropies in our calculations. Our measurements were performed at 53 °C, so we used the material parameters of 10O8 corresponding to the same temperature in our simulations, namely: $K_{11} = 8.54$ pN, $K_{22} = 3.83$ pN, $K_{33} = 10.6$ pN, $\epsilon_a = -0.48$, and $\chi_a = 9.65 \times 10^{-7}$.

The compound 10O8 was studied in a sandwich cell with ITO electrodes coated with rubbed polyimide layers for planar alignment. The electrode area was 5 mm x 5 mm. The thickness of the empty cell ($d = 19.5 \mu\text{m}$) was measured by interferometry using an Ocean Optics spectrophotometer. During the experiments, the sample was held in a custom-made heat stage that provided a constant temperature with a precision better than 0.1 °C. The heat stage was placed between the two poles of an electromagnet capable of producing a maximum homogeneous magnetic inductance of $B = 1$ T at the sample position. The magnetic inductance was measured by an Al-phalab 100 Gaussmeter. The magnetic field lay in the plane of the liquid crystal cell due to mechanical constraints. By rotating and fixing the stage, the angle between the magnetic field and the rubbing direction could be adjusted. Our measurements were performed in three geometries where this angle was set to 0°, 45°, and 90°, henceforth denoted as the parallel (\parallel), the oblique, and the perpendicular (\perp) geometries, respectively (Fig. 2).

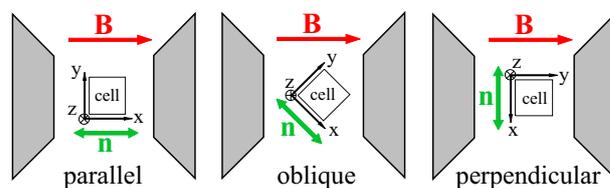


Fig. 2 (Color online) The schematics of the measurement geometries referred to as parallel, oblique, and perpendicular. The plane of the sandwich cell lies in the plane of the figure (x-y plane), the observation direction and the electric field are parallel to the z-axis.

*The same compound was abbreviated as 1/8 by Kochowska et al.³⁸. Here we rather follow the alternative nomenclature used by others^{37,39,40}.

DC voltage (U) was applied to the cell using the function generator output of a TiePie Handyscope HS3 device via a high-voltage amplifier. The sample was observed using a Questar QM100 long range microscope in transmission mode with white light illumination. The electric field-induced patterns were visualized by the shadowgraph technique⁴¹, without using any polarizers in the present case. The micrographs were recorded by a Foculus FO323B digital camera.

In each geometry, for a given value of magnetic field, voltage scans with 0.2 V steps were performed on a predefined voltage interval. After each voltage step, the DC driving was kept constant for 5 seconds before recording the image.

3 Theoretical model

In order to understand the physics of flexoelectric pattern formation in the presence of external magnetic field, one has to calculate the director distortions under the joint action of electric and magnetic fields.

A planar cell filled with a nematic liquid crystal is considered in a three-dimensional Cartesian coordinate system. The x-axis coincides with the rubbing direction, and the cell lies in the x-y plane. We assume strong anchoring of the director and no pretilt at the boundaries. The general director field $\mathbf{n} = \mathbf{n}(x, y, z)$ is represented by the tilt angle θ and the azimuthal (twist) angle ϕ :

$$\mathbf{n} = (\cos \theta \cos \phi, \cos \theta \sin \phi, \sin \theta). \quad (2)$$

Then, the initial homogeneous orientation \mathbf{n}_0 corresponds to $\theta = \phi = 0$, and both θ and ϕ should remain zero at the boundaries, even in the distorted state.

A homogeneous magnetic inductance $\mathbf{B} = (B_{\parallel}, B_{\perp}, 0)$ parallel to, and a homogeneous electric field

$$\mathbf{E} = (0, 0, E_z) \quad (3)$$

perpendicular to the cell plane are considered. Naturally, the assumption on the homogeneity of the electric field is appropriate until the variation in the z-component of the director remains very small inside the cell, which is valid if $U \lesssim U_c$.

Since flexodomains represent an equilibrium deformation, the final state can be calculated by minimizing the free energy. In our case, the density of free energy (f) is given by the sum of the elastic (f_{elast}), dielectric (f_{electr}), flexoelectric (f_{flexo}), and magnetic (f_{magn}) contributions:

$$f = f_{elast} + f_{diel} + f_{flexo} + f_{magn} \quad (4)$$

$$f_{elast} = \frac{1}{2}K_{11}(\nabla\mathbf{n})^2 + \frac{1}{2}K_{22}(\mathbf{n}(\nabla \times \mathbf{n}))^2 + \frac{1}{2}K_{33}(\mathbf{n} \times (\nabla \times \mathbf{n}))^2 \quad (5)$$

$$f_{diel} = -\frac{1}{2}\epsilon_0\epsilon_a(\mathbf{nE})^2 \quad (6)$$

$$f_{flexo} = -e_1\mathbf{nE}(\nabla\mathbf{n}) + e_3(\mathbf{n} \times (\nabla \times \mathbf{n}))\mathbf{E} \quad (7)$$

$$f_{magn} = -\frac{1}{2}\frac{\chi_a}{\mu_0}(\mathbf{nB})^2. \quad (8)$$

The Frank elastic constants K_{11} , K_{22} , and K_{33} correspond to the splay, twist, and bend director deformations, respectively. The permittivity and permeability of vacuum are denoted by ϵ_0 and μ_0 , respectively. For the minimization of the free energy the Euler-Lagrange formalism is used.

The characteristic parameters of the flexodomains, namely their threshold voltage U_c and the critical wave vector \mathbf{q}_c at the onset of the flexoelectric instability, can be obtained via a linear stability analysis with respect to periodic director deformations. These detailed calculations will be performed below for two special cases, the parallel and the perpendicular geometries of Fig. 2.

3.1 The parallel geometry

In the parallel geometry, the magnetic inductance is

$$\mathbf{B} = (B_{\parallel}, 0, 0). \quad (9)$$

Assuming $\chi_a > 0$, no magnetic Fredericksz transition is expected in this geometry; thus, the modulated director field of flexodomains emerges from a homogeneous planar basic state. The stripes of FDs are assumed to remain parallel to the rubbing direction, $\mathbf{q}_c = (0, q, 0)$. Consequently, all variables depend only on the y- and z-coordinates. The free energy is minimized by solving the system of Euler-Lagrange equations:

$$\frac{d}{dy} \left(\frac{\partial f}{\partial \theta_y} \right) + \frac{d}{dz} \left(\frac{\partial f}{\partial \theta_z} \right) - \frac{\partial f}{\partial \theta} = 0, \quad (10)$$

$$\frac{d}{dy} \left(\frac{\partial f}{\partial \phi_y} \right) + \frac{d}{dz} \left(\frac{\partial f}{\partial \phi_z} \right) - \frac{\partial f}{\partial \phi} = 0, \quad (11)$$

where spatial partial derivatives are denoted in the lower indices by commas and the corresponding space coordinates.

Combining eqs. (2)-(11) results in a complicated system of nonlinear partial differential equations that has to be further processed as follows. Near the onset of flexodomains, the director distortions are small and their periodic part characterized by the wave number q can be separated from the z-dependent amplitudes of the tilt ($\theta_0(z)$) and twist ($\phi_0(z)$) modulations via:

$$\theta(y, z) = \theta_0(z) \cos(qy), \quad (12)$$

$$\phi(y, z) = \phi_0(z) \sin(qy). \quad (13)$$

The director deformation profile of FDs in the middle of the cell ($z = 0$) is visualized in Fig. 3. Using the above ansatz, eqs. (10)-(11) can be linearized with respect to the small quantities θ_0 and ϕ_0 . After switching to the dimensionless space

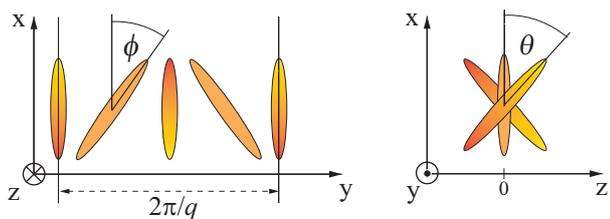


Fig. 3 (Color online) The director profile of flexodomains in the middle of the cell ($z = 0$) in two views. The director is symbolized by ellipses. The electric field is parallel to the z -direction.

variable $\hat{z} = z\pi/d$ and wave number $\hat{q} = qd/\pi$, straightforward calculations result in:

$$\phi_0'' = 2 \frac{\delta K \hat{q}}{1 - \delta K} \theta_0' - \frac{U e^* \hat{q}}{K_{av} (1 - \delta K) \pi} \theta_0 + \left(\left(\frac{B_{\parallel}}{B_t} \right)^2 + \frac{(1 + \delta K) \hat{q}^2}{1 - \delta K} \right) \phi_0, \quad (14)$$

$$\theta_0'' = -2 \frac{\delta K \hat{q}}{1 + \delta K} \phi_0' - \frac{U e^* \hat{q}}{K_{av} (1 + \delta K) \pi} \phi_0 + \left(\left(\frac{B_{\parallel}}{B_s} \right)^2 - \left(\frac{U}{U_s} \right)^2 + \frac{(1 - \delta K) \hat{q}^2}{1 + \delta K} \right) \theta_0, \quad (15)$$

where $K_{av} = (K_{11} + K_{22})/2$, and $\delta K = (K_{11} - K_{22})/(K_{11} + K_{22})$. In this final system of ordinary differential equations, prime and double prime denote the first and second \hat{z} -derivatives, respectively. In addition, the following scaling quantities are introduced: $B_s = \frac{\pi}{d} \sqrt{\frac{\mu_0 K_{11}}{\chi_a}}$, $B_t = \frac{\pi}{d} \sqrt{\frac{\mu_0 K_{22}}{\chi_a}}$, and $U_s = \pi \sqrt{\frac{K_{11}}{\epsilon_0 \epsilon_a}}$. They are formally similar to the expressions for the threshold magnetic inductances of the magnetic splay (B_s), the magnetic twist (B_t) transitions, and the threshold voltage U_s of the electric splay Freedericksz transition. The applied voltage corresponds to $U = E_z d$.

The cell is symmetric with respect to its midplane, therefore it is sufficient to perform the calculations for only one half of the cell. For a given value of \hat{q} and U , the system of eqs. (14)-(15) was numerically solved for $\phi_0(\hat{z})$ and $\theta_0(\hat{z})$ in Matlab on the interval $\hat{z} = [-\pi/2, 0]$, which corresponds to the lower half of the planar cell. Mixed boundary conditions were used as follows: $\theta_0(-\pi/2) = \phi_0(-\pi/2) = 0$ and $\theta_0'(0) = \phi_0'(0) = 0$.

For $U < U_{c||\hat{q}}$ the homogeneous director field is stable, thus $\phi_0(\hat{z}) = \theta_0(\hat{z}) = 0$. The critical voltage $U_{c||\hat{q}}$ is identified by the nonzero solutions of the director modulation amplitudes $\phi_0(\hat{z})$ and $\theta_0(\hat{z})$, showing the emergence of the pattern. Since our model is linearized, no quantitative information can be obtained about the director field above the critical voltage.

Calculating $U_{c||\hat{q}}$ as the function of \hat{q} yields a neutral curve with a minimum corresponding to the actual critical voltage

$U_{c||}$ and wave number $\hat{q}_{c||}$. As an example, the $U_{c||\hat{q}}$ vs. \hat{q} curve is shown for $B_{\parallel} = 0$ T (solid line), 0.25 T (dotted line), 0.375 T (dashed line), and 0.5 T (dash-dotted line) in Fig. 4. The red crosses show $U_{c||}$ and $\hat{q}_{c||}$ for each value of the applied parallel magnetic inductance. The calculations were performed with the material parameters of 1008 listed in Sec. 2 and $e^* = 6.9$ pC/m.

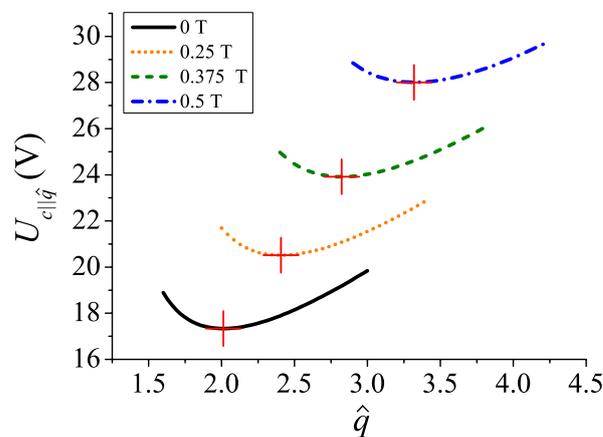


Fig. 4 (Color online) The critical voltages ($U_{c||\hat{q}}$) of flexodomains for different wave numbers in the case of $B_{\parallel} = 0$ T (solid line), 0.25 T (dotted line), 0.375 T (dashed line), and 0.5 T (dash-dotted line). For a given magnetic inductance, the red cross shows the smallest critical voltage $U_{c||}$ at the critical wave number $\hat{q}_{c||}$ that should actually be realized by the system.

It can be clearly seen in Fig. 4 that both $U_{c||}$ and $\hat{q}_{c||}$ increase with higher values of B_{\parallel} .

3.2 The perpendicular geometry

In the perpendicular geometry, the magnetic inductance is given by:

$$\mathbf{B} = (0, B_{\perp}, 0). \quad (16)$$

The main difference to the parallel case is that here the magnetic field does not stabilize the initial homogeneous planar configuration; instead it induces a twist Freedericksz transition.

As a consequence, in the absence of the electric field, the director can be described solely by a \hat{z} -dependent twist angle $\psi = \psi(\hat{z})$, i.e. $\mathbf{n} = (\cos \psi, \sin \psi, 0)$. Determination of the director profile via minimization of the free energy is a well-known procedure; $\psi(\hat{z})$ can be obtained as the solution of the second order nonlinear ordinary differential equation⁴²:

$$\psi'' = - \left(\frac{B_{\perp}}{B_t} \right)^2 \cos \psi \sin \psi \quad (17)$$

with the boundary conditions: $\psi_0(-\pi/2) = 0$ and $\psi_0'(0) = 0$.

Fig. 5 shows the resulting $\psi(z)$ profile inside the cell calculated with the parameters of our particular material (10O8) for three different values of the applied magnetic inductance.

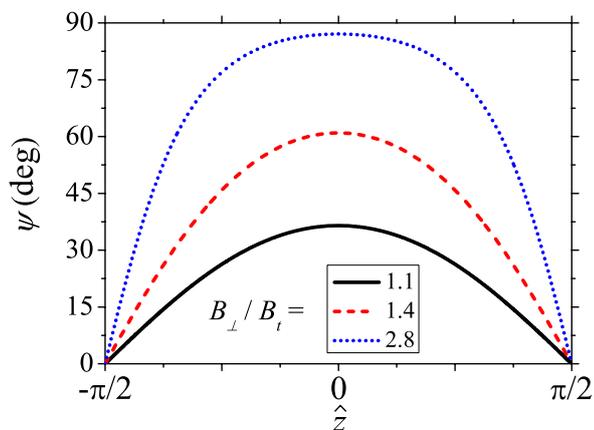


Fig. 5 (Color online) The twist angle ψ versus the cross section direction z of the planar cell in the case of different perpendicularly applied magnetic inductances.

For $B_{\perp} < B_t$, the twist angle naturally equals zero. Above the Freedericksz threshold field, ψ increases and reaches its maximum in the middle of the cell: $\psi_m = \psi(0)$. At higher B_{\perp} , ψ_m approaches 90° , but in the largest part of the cell, the twist angle is still significantly below 90° ; even at $B_{\perp}/B_t = 2.78$ that corresponds to our maximum inductance of $B_{\perp} = 1$ T. Note that an electric field below the onset of FDs (i.e. $U < U_{c\parallel}$) does not affect the basic (homogeneous or twisted) state.

If $B_{\perp} < B_t$, the initial director configuration is homogeneous, thus the director modulation caused by the onset of flexodomains can be described similarly to the parallel case, using eq. (2). Above the Freedericksz threshold, however, the periodic structure of FDs emerges from a twisted director field, hence:

$$\mathbf{n} = (\cos \theta \cos(\psi + \phi), \cos \theta \sin(\psi + \phi), \sin \theta), \quad (18)$$

where $\theta = \theta(x, y, z)$ and $\phi = \phi(x, y, z)$ now depend on all space coordinates. The free energy minimization can be done by the system of Euler-Lagrange equations:

$$\frac{d}{dx} \left(\frac{\partial f}{\partial \theta_x} \right) + \frac{d}{dy} \left(\frac{\partial f}{\partial \theta_y} \right) + \frac{d}{dz} \left(\frac{\partial f}{\partial \theta_z} \right) - \frac{\partial f}{\partial \theta} = 0, \quad (19)$$

$$\frac{d}{dx} \left(\frac{\partial f}{\partial \phi_x} \right) + \frac{d}{dy} \left(\frac{\partial f}{\partial \phi_y} \right) + \frac{d}{dz} \left(\frac{\partial f}{\partial \phi_z} \right) - \frac{\partial f}{\partial \phi} = 0. \quad (20)$$

In eqs. (19)-(20), additional terms appear compared to eqs. (10)-(11) in the parallel case, due to the x -dependence of the angles θ and ϕ . The combination of eqs. (3)-(8) and (16)-(20) leads to lengthy expressions that must be linearized next in

order to have a chance to calculate the threshold parameters of FDs.

In the perpendicular geometry we still assume that the flexoelectric instability results in unidirectional stripes, but in contrast to the parallel case, the stripes are allowed to run at an angle β with respect to the initial planar director \mathbf{n}_0 , i.e. $\mathbf{q}_c = (q \sin \beta, q \cos \beta, 0)$. Hence the following ansatz is applied to the θ and ϕ angles:

$$\theta(x, y, z) = \theta_0(z) \cos((q \cos \beta)y - (q \sin \beta)x), \quad (21)$$

$$\phi(x, y, z) = \phi_0(z) \sin((q \cos \beta)y - (q \sin \beta)x). \quad (22)$$

Switching again to dimensionless variables as in Sec. 3.1, after straightforward calculations one obtains the system of ordinary differential equations:

$$\begin{aligned} \phi_0'' = & \hat{q} \theta_0 \left(\left(1 - \frac{\kappa}{1 - \delta K} \right) \psi' \sin(\beta - \psi) \right. \\ & - \frac{e^* U \cos(\beta - \psi)}{(1 - \delta K) K_{av} \pi} \left. \right) + \phi_0 \left(\frac{\kappa \hat{q}^2 \sin^2(\beta - \psi)}{1 - \delta K} \right. \\ & + \frac{(1 + \delta K) \hat{q}^2 \cos^2(\beta - \psi)}{1 - \delta K} - \left. \left(\frac{B_{\perp}}{B_t} \right)^2 \cos(2\psi) \right) \\ & + \frac{2\delta K \hat{q} \theta_0' \cos(\beta - \psi)}{1 - \delta K} \end{aligned} \quad (23)$$

$$\begin{aligned} \theta_0'' = & \hat{q} \phi_0 \left(\frac{(1 - 3\delta K - \kappa) \psi' \sin(\beta - \psi)}{1 + \delta K} \right. \\ & - \frac{e^* U \cos(\beta - \psi)}{(1 + \delta K) K_{av} \pi} \left. \right) + \theta_0 \left(\frac{\kappa \hat{q}^2 \sin^2(\beta - \psi)}{1 + \delta K} \right. \\ & + \frac{(1 - \delta K) \hat{q}^2 \cos^2(\beta - \psi)}{1 + \delta K} + \frac{(2\delta K + \kappa - 2)(\psi')^2}{1 + \delta K} \\ & + \left. \left(\frac{B_{\perp}}{B_s} \right)^2 \sin^2(\psi) - \left(\frac{U}{U_s} \right)^2 \right) \\ & - \frac{2\delta K \hat{q} \phi_0' \cos(\beta - \psi)}{1 + \delta K}, \end{aligned} \quad (24)$$

where an additional constant $\kappa = K_{33}/K_{av}$ was introduced.

Below the twist Freedericksz threshold, the procedure to find $U_{c\perp}$ and $\hat{q}_{c\perp}$ for different values of B_{\perp} is similar to that discussed in Sec. 3.1, as β and ψ can be fixed to zero. If $B_{\perp} > B_t$, however, ψ and ψ' have to be taken from the solution of eq. (17). Calculating $U_{c\perp} \hat{q}_{c\perp}$ as the function of \hat{q} and β gives a surface with a minimum that corresponds to the actual critical voltage $U_{c\perp}$, wave number $\hat{q}_{c\perp}$, and stripe angle $\beta_{c\perp}$.

As an example, $U_{c\perp} \hat{q}_{c\perp}$ is plotted as the function of \hat{q} and β for $B_{\perp} = 0.7$ T in Fig. 6. The calculations were performed

using the material parameters of 1008 presented in Sec. 2 and $e^* = 6.8$ pC/m. The minimum is clearly seen at around the middle of the surface.

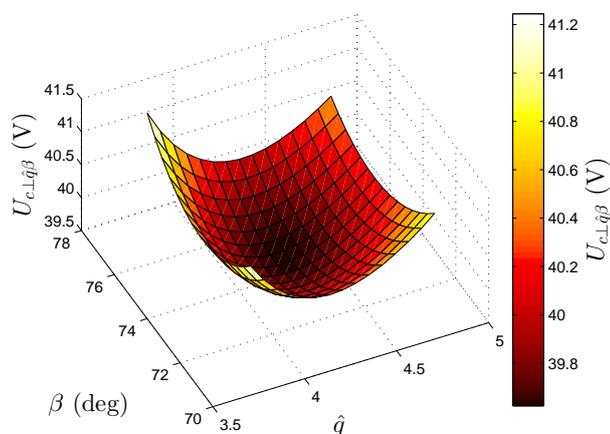


Fig. 6 (Color online) The critical voltages ($U_{c\perp\hat{q}\beta}$) of flexodomains for different wave numbers \hat{q} and stripe angles β in the case of $B_{\perp} = 0.7$ T. The minimum of the surface in the center corresponds to the actual threshold of the flexoelectric instability.

4 Experimental results

4.1 Parallel geometry

Snapshots of flexodomains taken at $B_{\parallel} = 0$ T ($U = 23$ V) and $B_{\parallel} = 1$ T ($U = 52.6$ V) are presented in Fig. 7a and c. The micrographs were captured slightly above the threshold voltages ($U_{c\parallel}$) of the patterns in the parallel geometry, covering an area of $106\ \mu\text{m} \times 106\ \mu\text{m}$. The two-dimensional Fourier transforms (amplitude spectra) of the images Fig. 7a and c are shown in Fig. 7b and d, respectively.

It can immediately be seen in Fig. 7 that the dimensionless wave number \hat{q} of FDs is significantly larger at $B_{\parallel} = 1$ T than at zero magnetic field, however, the direction of the wave vector remains the same as expected. The threshold voltage is also larger at the higher B_{\parallel} . In order to precisely determine the threshold parameters $U_{c\parallel}$ and $\hat{q}_{c\parallel}$, the emergence of the pattern has to be followed as the function of the applied voltage. The proper analysis of this process needs a definition of a quantity that can be used to indicate the presence of a pattern. In our case, this quantity was assigned to the maximal Fourier amplitude (C_{FFT}) in a broad region in that part of the Fourier space where the peaks for FDs were expected. The value of C_{FFT} is essentially a measure of contrast that is expected to be minimal in the homogeneous initial state, and to increase with the emergence of the pattern.

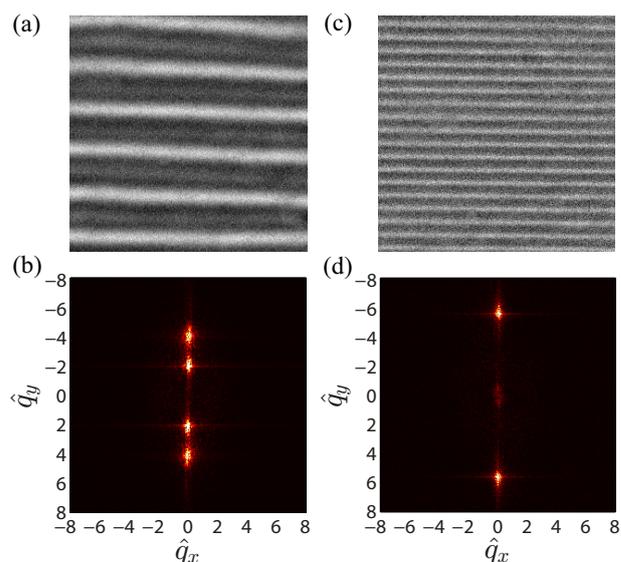


Fig. 7 (Color online) Micrographs of flexodomains taken at (a) $B_{\parallel} = 0$ T ($U = 23$ V) and (c) $B_{\parallel} = 1$ T ($U = 52.6$ V) in the parallel geometry. The images cover an area of $106\ \mu\text{m} \times 106\ \mu\text{m}$. The magnetic field and the rubbing direction lie parallel to the horizontal direction. The two dimensional Fourier transforms of (a) and (c) are shown in (b) and (d), respectively.

The measured voltage dependence of C_{FFT} is shown in Fig. 8 for different values of B_{\parallel} . We note that here C_{FFT} is background corrected, which means that the maximal Fourier amplitude of the snapshot taken in the homogeneous initial state is subtracted from all measured values.

The threshold behavior can be observed in Fig. 8 for all different values of B_{\parallel} . Below the appearance of the patterns, the contrast equals the background value, thus $C_{FFT} = 0$. At higher voltages, the emergence of FDs is indicated by an increase in the contrast. The critical voltages $U_{c\parallel}$ (versus B_{\parallel}) were determined by extrapolation of the lines fitted on the linear parts of the $C_{FFT}(U)$ functions for each value of B_{\parallel} (dashed lines in Fig. 8).

The \hat{q} data were obtained by fitting the peaks in the Fourier transforms of micrographs with 2D Gaussian surfaces for each applied voltage. The fitted centres of the Gaussians were used to acquire the values of \hat{q} . In Fig. 9, the wave numbers of FDs are plotted as the function of the reduced voltage $U/U_{c\parallel}$ for several values of B_{\parallel} . The data show that the wave number increases linearly with the applied voltage above the threshold. Therefore, the critical wave number $\hat{q}_{c\parallel}$ should be determined by extrapolation to $U/U_{c\parallel} = 1$. The extrapolating dashed lines in Fig. 9 were fitted to the data points lying in the range $1.02 < U/U_{c\parallel} < 1.06$, which is approximately the same interval as the one used in the extrapolation to determine $U_{c\parallel}$ (see Fig. 8).

Applying the procedure presented above on a number of

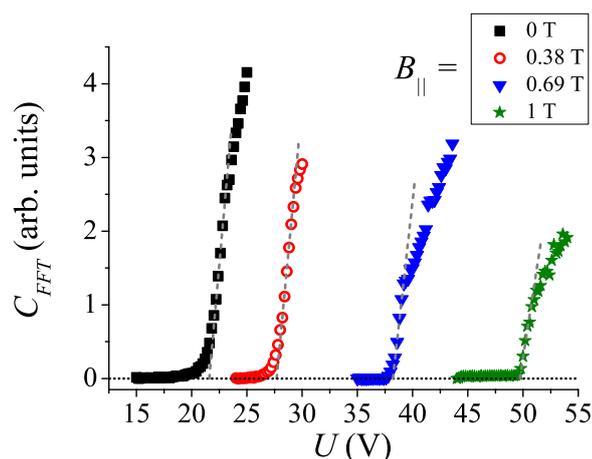


Fig. 8 (Color online) The voltage dependence of the pattern contrast (symbols) based on the maximal Fourier amplitude (C_{FFT}) for different applied magnetic inductances in the parallel geometry. The dashed lines indicate the linear extrapolation.

different B_{\parallel} values, the magnetic field dependence of the threshold parameters can be determined. Figs. 10a and b depict how B_{\parallel} affects $U_{c\parallel}$ and $\hat{q}_{c\parallel}$, respectively. The solid symbols show the experimentally obtained data.

In order to see how the experimental results match our theoretical considerations, the threshold parameters $U_{c\parallel}$ and $\hat{q}_{c\parallel}$ were determined by the simulation technique described in Sec. 3.1 using the material parameters of 1008 listed in Sec. 2. Only the parameter e^* , i.e. the difference of flexoelectric coefficients, was determined by fitting our theoretical model to the measured value of $\hat{q}_{c\parallel}$ at $B_{\parallel} = 0$. Our method gave $e^* = 6.9$ pC/m, which was used in the simulations of the parallel geometry. The open symbols in Fig. 10a and b show the magnetic inductance dependence of the critical voltage and the wave number obtained from the simulation (the connecting lines are used to guide the eye).

It is seen in Fig. 10 that the theoretical $U_{c\parallel}(B)$ dependence is nicely reproduced experimentally; $U_{c\parallel}$ increases monotonically with B_{\parallel} , but the measured threshold voltages are systematically larger than the theoretical ones. This deviation can be attributed to the ionic conductivity of the liquid crystal and to the structure of the cell. Though in many situations liquid crystals can be considered insulators, the finite conductivity of nematics becomes important if a low frequency AC voltage is applied onto the material⁴³. The effect is even more apparent when a DC voltage is used. Common liquid crystals, such as 1008, exhibit electrolytic conductivity where the charge carriers are ionic impurities. If the applied electric field changes very slowly or is constant in time, ions with opposite charges have time to reach the opposite electrodes, where they can accumulate, forming a Debye layer. This screening

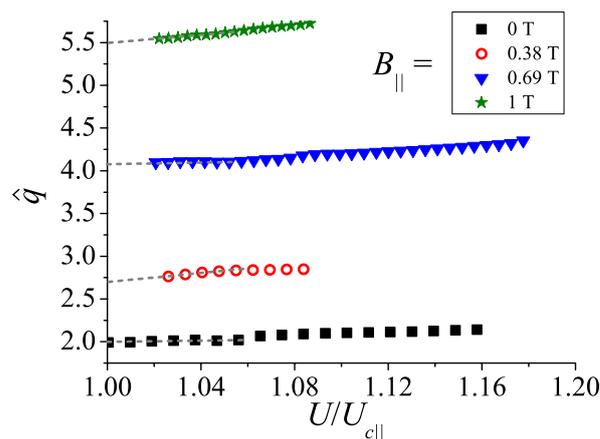


Fig. 9 (Color online) The wave number of flexodomains as a function of the reduced voltage (symbols) for different applied magnetic inductances in the parallel geometry. The dashed lines indicate the linear extrapolation.

may reduce the electric field in the cell. However, if the total number of charge carriers is sufficiently low, this effect is negligible. In typical liquid crystal test cells, the ITO electrodes are coated with electrically insulating polyimide layers. The thickness of these are approximately 100 – 120 nm that can provide barriers strong enough to stop ions and minimize the charge transfer from the electrodes²⁸. In the static case, the voltage U applied on the cell should be larger than that on the liquid crystal itself (U_{LC}), because of the voltage drop at the polyimide and the Debye layers. The internal voltage attenuation may be estimated by $U_{LC}/U = R_{LC}/(R_b + R_{LC})$, where R_{LC} and R_b are the resistances of the liquid crystal and of the boundary layers, respectively. This simple model can explain why systematically larger critical voltages were obtained in the experiments compared to the simulations.

Another peculiarity seen in Figs. 10a is that the difference between the experimental and calculated critical voltages is larger at lower applied voltages. This effect is consistent with the above model. Increasing the applied DC voltage decreases the effective number of charge carriers and thus increases R_{LC} , while R_p might be regarded as voltage independent. Consequently, the internal attenuation reduces; the ratio U_{LC}/U approaches 1 when the applied voltage increases.

Besides the critical voltage, the wave number $\hat{q}_{c\parallel}$ also shows a significant increase with the applied magnetic field (see Figs. 7 and 10). This tendency is the consequence of the monotonically increasing $U_{c\parallel}(B_{\parallel})$; higher voltages may allow higher wave numbers. The simulation results agree very well with the experimental data. It should be noted that the calculated magnetic field dependence of $\hat{q}_{c\parallel}$ in Fig. 10b is not a fit; the material parameters used were not varied in order to achieve

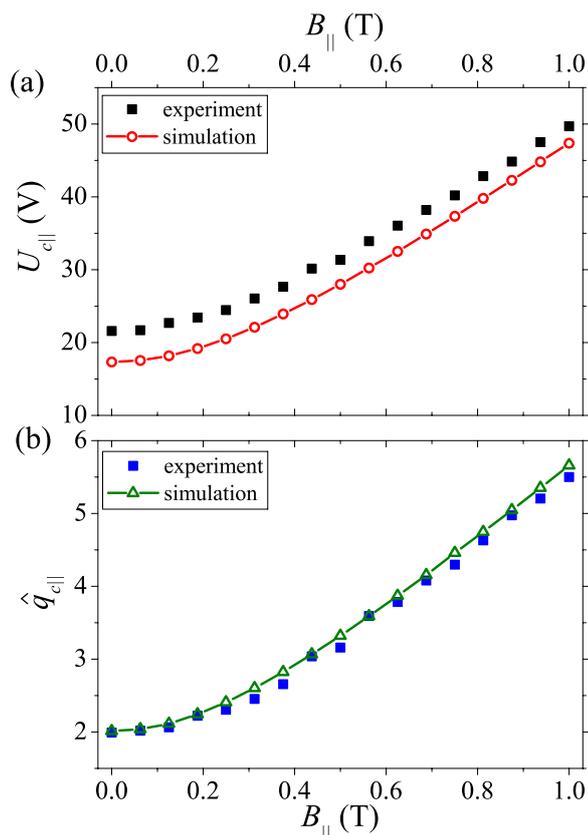


Fig. 10 (Color online) The magnetic inductance dependence of (a) the critical voltage and (b) the wave number in the parallel geometry. The solid (connected open) symbols were obtained by experiments (by numerical simulations).

a better match with the measured results. This implies that a fine tuning of the elastic constants and the other parameters may result in even better agreement.

4.2 The oblique geometry

In Figs. 11a, b, c and d, micrographs of FDs of the oblique geometry can be seen that were taken at $B_{obl} = 0$ T ($U = 23$ V), $B_{obl} = 0.3$ T ($U = 27.6$ V), $B_{obl} = 0.6$ T ($U = 38.8$ V) and $B_{obl} = 1$ T ($U = 54.8$ V), respectively. The images were recorded slightly above the threshold voltages of flexodomains, and they cover an area of $106 \mu\text{m} \times 106 \mu\text{m}$, similarly to the ones presented in the previous subsection of the parallel geometry. In Figs. 11a-d, one can clearly identify the most spectacular feature of the oblique geometry: not only the wave number of the FD stripes is influenced by the magnetic field, but the direction of the wave vector as well.

In the oblique geometry, the threshold voltages U_{cobl} and the critical wave numbers \hat{q}_{cobl} were determined following the

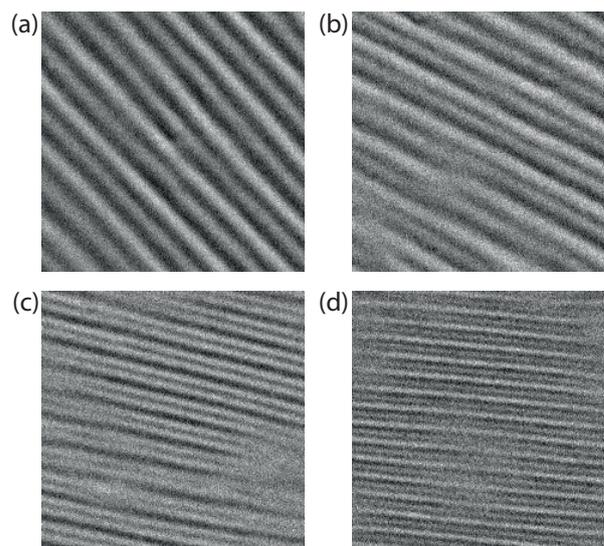


Fig. 11 Micrographs of flexodomains taken at (a) $B_{obl} = 0$ T ($U = 23$ V), (b) $B_{obl} = 0.3$ T ($U = 27.6$ V), (c) $B_{obl} = 0.6$ T ($U = 38.8$ V) and (d) $B_{obl} = 1$ T ($U = 54.8$ V) in the oblique geometry. The images cover an area of $106 \mu\text{m} \times 106 \mu\text{m}$. The magnetic field lies in the horizontal direction. The rubbing direction is at an angle of 45° with respect to the horizontal direction (parallel to the stripes in (a)).

procedure presented in Sec. 4.1 in conjunction with Figs. 8 and 9. In contrast to the parallel case, the angle β_{obl} between \mathbf{n}_0 and the flexoelectric stripes had to be measured too.

The dependence of the stripe direction β_{obl} on the reduced voltage U/U_{cobl} is plotted in Fig. 12 for different magnetic inductances. At nonzero values of B_{obl} , the angle β_{obl} shows a decreasing tendency by increasing U/U_{cobl} . Therefore the stripe direction angle at the onset of the flexoelectric patterns (β_{cobl}) can be determined by extrapolation (see the dashed lines in Fig. 12), analogously to the determination of \hat{q}_{cobl} .

The magnetic inductance dependence of the threshold parameters U_{cobl} and \hat{q}_{cobl} can be seen in Fig. 13a. The critical voltage increases with B_{obl} ; \hat{q}_{cobl} exhibits a similar character. The tendency of increasing critical voltage and wave number at high magnetic fields is similar to that found in the parallel geometry and is due to the stabilizing magnetic torques.

The stripe angle β_{cobl} at the threshold versus the magnetic inductance is shown in Fig. 13b. The data indicate that β_{cobl} increases with B_{obl} monotonically from zero and it approaches 45° at high fields.

In the oblique geometry, a pure magnetic field induces a thresholdless, homogeneous twist deformation. Therefore, for $B_{obl} \neq 0$, a twisted structure forms the basic state of the flexoelectric instability at $U = U_{cobl}$. For high magnetic fields, the director realigns to be parallel to \mathbf{B}_{obl} , i.e. the maximal rotation angle is 45° . Fig. 13b clearly shows that β_{cobl} follows the

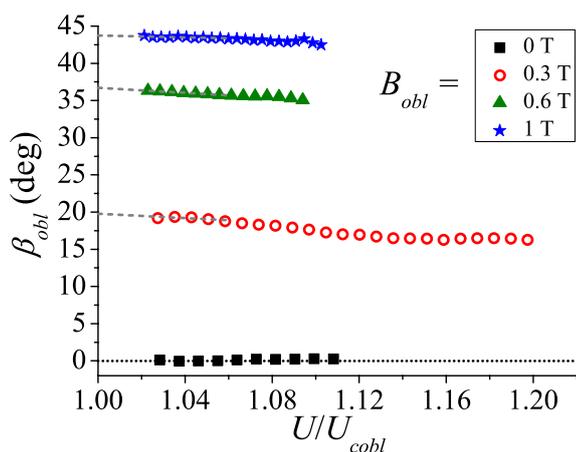


Fig. 12 (Color online) The angle of FD stripes with respect to the rubbing direction as the function of the reduced voltage (symbols) for different applied magnetic inductances in the oblique geometry. The dashed lines indicate the linear extrapolation.

director rotation and saturates approaching the same 45° angle; thus, at large magnetic fields, the FD stripes are parallel to the (average) director, just as in the case of $B_{obl} = 0$.

4.3 The perpendicular geometry

Micrographs of flexodomains of the perpendicular geometry recorded slightly above their critical voltage at $B_{\perp} = 0$ T ($U = 24$ V), $B_{\perp} = 0.2$ T ($U = 22.4$ V), $B_{\perp} = 0.35$ T ($U = 18.4$ V), $B_{\perp} = 0.5$ T ($U = 31.6$ V), $B_{\perp} = 0.75$ T ($U = 45.6$ V) and $B_{\perp} = 1$ T ($U = 56$ V) are shown in Figs. 14a, b, c, d, e, and f, respectively. All images cover an area of $106\ \mu\text{m} \times 106\ \mu\text{m}$ (the same as in Figs. 7 and 11). The direction of the rubbing (\mathbf{n}_0) and that of the magnetic field (B_{\perp}) correspond to the vertical and the horizontal directions, respectively.

One can observe in Figs. 14a-c that the distance between stripes increases, but the orientation of flexodomains remains parallel to the rubbing direction. In contrast, in Figs. 14d-f, the wave number of the pattern increases and the stripes become oblique, gradually approaching to be horizontal.

The critical parameters $U_{c\perp}$, $\hat{q}_{c\perp}$, and $\beta_{c\perp}$ versus B_{\perp} were determined by following the same procedure presented in the previous subsections. The experimental values of the critical voltage, wave number and stripe angle can be seen as the function of B_{\perp} in Figs. 15a, b, and c, respectively (solid symbols).

The threshold parameters $U_{c\perp}$, $\hat{q}_{c\perp}$, and $\beta_{c\perp}$ were also determined by the simulation technique described in Sec. 3.2. The same material constants were used as for the parallel geometry, except e^* . A slightly different value of $e^* = 6.8$ pC/m was used here (instead of 6.9 pC/m), in order to fit the experimental value of the critical wave number in the perpendicular geometry at zero magnetic field, which differed slightly

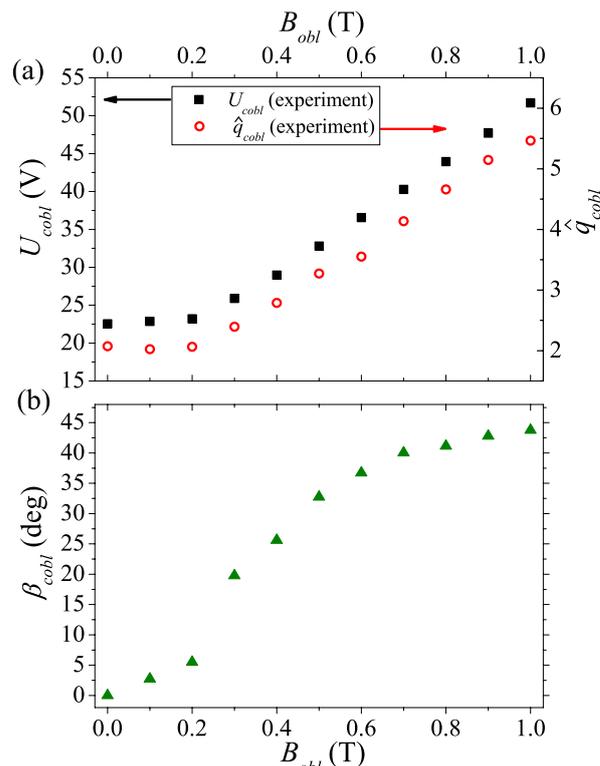


Fig. 13 (Color online) The magnetic inductance dependence of (a) the critical voltage, wave number and (b) FD stripe angle with respect to the rubbing direction in the oblique geometry.

from that measured earlier in the parallel geometry. The open symbols in Figs. 15a, b, and c show the magnetic inductance dependence of the critical voltage, wave number, and stripe angle obtained from the simulations (the connecting lines are just guides for the eye).

It is clear from Fig. 15 that the characteristics of the flexoelectric patterns are different below and above the threshold magnetic inductance ($B_t = 0.36$ T) of the twist Fredericksz transition. Nevertheless, for both B_{\perp} ranges, the theoretical curves nicely reproduce the experimental dependence. In the range $B_{\perp}/B_t < 1$, $U_{c\perp}$ and $\hat{q}_{c\perp}$ decreases with increasing magnetic field, while the direction of the FD stripes remains parallel \mathbf{n}_0 , thus $\beta_{c\perp}$ is essentially zero. It is important to note that close to B_t , both $U_{c\perp}$ and $\hat{q}_{c\perp}$ are far below their values at $B_{\perp} = 0$. This decrease becomes clear if we invoke the structure of flexodomains. The periodic director deformation of FDs involves both tilt and twist components, as it was described by eqs. (12)-(13). The torque exerted by a bias magnetic field applied perpendicular to the initial director helps to twist the director and thus reduces the threshold voltage of FDs, even if it is still too low to induce a homogeneous twist deformation by itself.

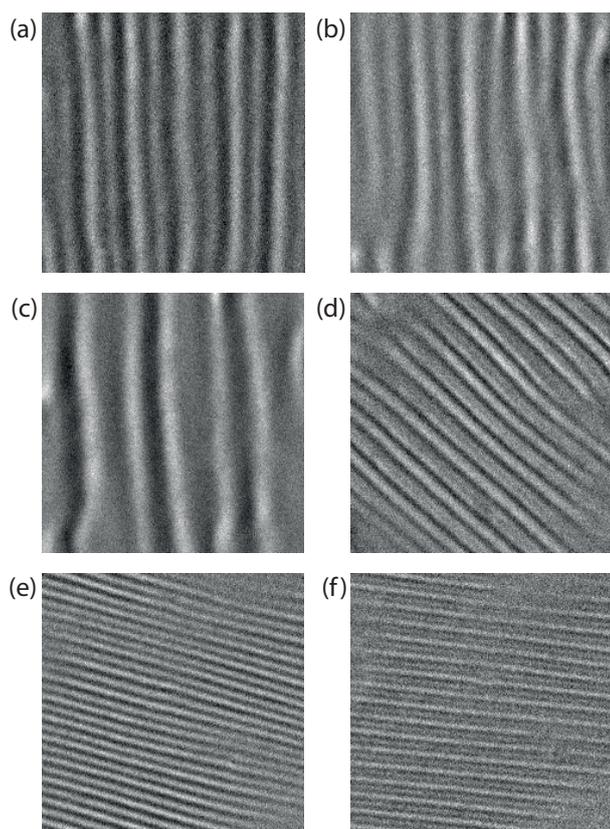


Fig. 14 Micrographs of flexodomains taken at (a) $B_{\perp} = 0$ T ($U = 24$ V), (b) $B_{\perp} = 0.2$ T ($U = 22.4$ V), (c) $B_{\perp} = 0.35$ T ($U = 18.4$ V), (d) $B_{\perp} = 0.5$ T ($U = 31.6$ V), (e) $B_{\perp} = 0.75$ T ($U = 45.6$ V) and (f) $B_{\perp} = 1$ T (and $U = 56$ V) in the perpendicular geometry. The images cover an area of $106 \mu\text{m} \times 106 \mu\text{m}$. The magnetic field and the rubbing direction lie parallel to the horizontal and the vertical directions, respectively.

Above the Fredericksz threshold, both $U_{c\perp}$ and $\hat{q}_{c\perp}$ increase with B_{\perp} . Furthermore, the orientation of the stripes changes gradually from the rubbing direction towards a state where they are more parallel to the magnetic field. Therefore, $\beta_{c\perp}$ increases from zero and approaches 90° at high values of B_{\perp} . In order to see how the critical rotation angle $\beta_{c\perp}$ of FDs is related to the twist deformed basic state of the director field, we included the maximal twist angle ψ_m as the function of B_{\perp} in Fig. 15c (solid line). It is clearly seen that ψ_m is always larger than $\beta_{c\perp}$, as expected. The difference between the stripe angle and the maximal twist angle is relatively small, in spite of the fact that the $\psi(\hat{z})$ profile is not flat, even at $B_{\perp} = 1$ T. This leads to the conclusion that the flexoelectric domains in our system are localized in the middle of the cell. As a consequence, the twist deformation of the director is directly visualized by the rotation of the FD stripes.

Though the numerically obtained $U_{c\perp}(B_{\perp})$ curves exhibit

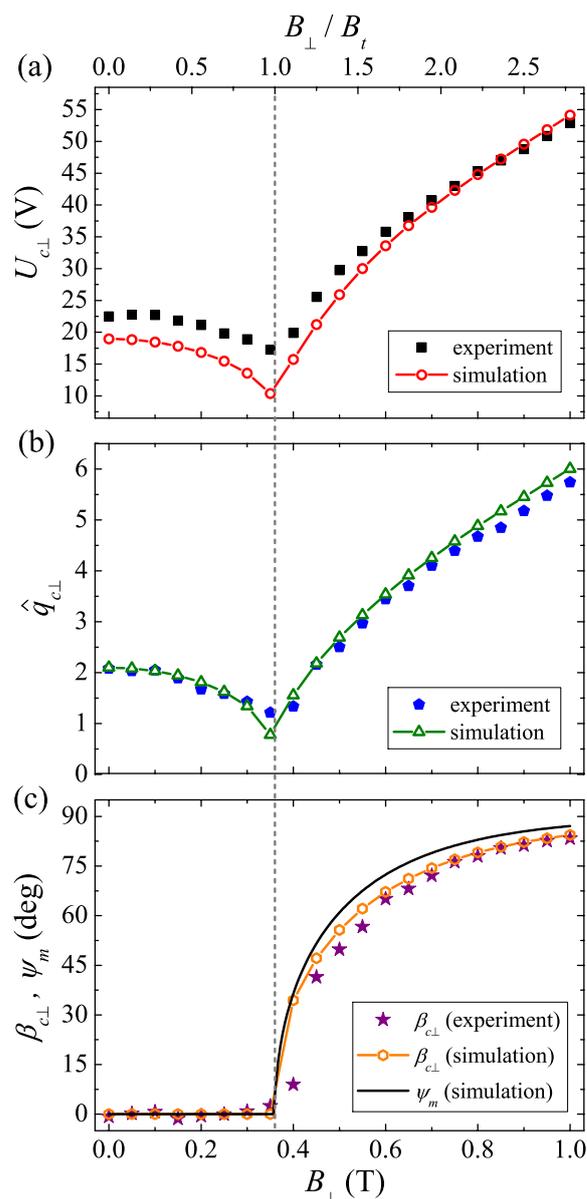


Fig. 15 (Color online) The magnetic inductance dependence of (a) the critical voltage, (b) wave number and (c) FD stripe angle with respect to the rubbing direction in the perpendicular geometry. The solid (connected open) symbols were obtained by experiments (numerical simulations).

a similar B -dependence as the experimental ones, the latter values are slightly, though systematically higher, just as it was found in the parallel geometry. The explanation given for the voltage deviation in Sec. 4.1 applies here as well. In contrast to the threshold voltages, the measured and calculated $\hat{q}_{c\perp}(B_{\perp})$ curves match almost perfectly, despite the fact that the B -dependent values were not obtained by a fit (no free pa-

rameters were varied in the simulations).

Similarly, a good agreement can be seen between the calculated and the measured $\beta_{c\perp}(B_{\perp})$ dependence as well, though the threshold of the twist Freedericksz transition seems to be less sharp in the experiment. This is most likely due to experimental imperfections, e.g. a slight misalignment of the magnetic field direction.

We note here that the vertical dashed line in Figs. 15a-c is not an experimental value of the threshold of the twist Freedericksz transition; it was calculated from the material parameters of 1008 listed in Sec. 2, which were taken from independent measurements³⁷.

5 Discussion

We showed in the previous sections that the presence of an additional magnetic field has a significant influence on the formation of flexodomains in a nematic liquid crystal. It is well known that a magnetic field affects the electric Freedericksz transitions as well in certain geometries. This is not surprising as, depending on its direction, the torque exerted by the magnetic field either stabilizes or destabilizes the initial state. In the following, we discuss these analogies in more detail.

Let us start with the magnetic field applied along \mathbf{n}_0 . Here, the critical voltage $U_{c\parallel}$ of FDs was found to increase monotonically with B_{\parallel} . Qualitatively similar behavior is expected in the same geometry for the homogeneous splay Freedericksz transition, assuming that the nematic compound exhibits positive dielectric and magnetic susceptibility anisotropies. There, the magnetic field has a stabilizing effect: it tends to suppress the director tilt and twist as well. Our findings point out that this stabilizing effect works similarly in the case of flexodomains, where director deformation is induced by flexoelectricity, acting against the negative dielectric anisotropy that stabilizes the homogeneous planar state.

The perpendicular geometry has some more interesting aspects. Our results show that the critical properties of FDs exhibit a completely different nature in the two distinct magnetic field ranges separated by the twist Freedericksz threshold field. For $B_{\perp} < B_t$, the critical voltage was found to decrease with B_{\perp} , while for $B_{\perp} > B_t$ an opposite tendency was detected. Comparing this with the splay Freedericksz transition of a nematic with $\epsilon_a > 0$, we do not find an analogy, in contrast to the parallel geometry. The threshold voltage for the homogeneous director reorientation is not affected by the magnetic field at all if $B_{\perp} < B_t$ ⁴⁴. This is due to the fact that the electric splay Freedericksz distortion involves only the tilt of the director, while in FDs tilt and twist are both present. A magnetic inductance below B_t cannot create twist, but may alter twist if it is already present.

Measurements in the oblique and perpendicular geometries showed that the direction of the FD stripes rotate if there

is a twist deformation in the sample. This unambiguously proves that the FDs observed are of bulk origin, just as it was assumed in the first theoretical interpretation¹⁶. Thus, our findings are in contrast to some recent results of flexoelectric pattern formation in bent-core nematic compounds using twisted cells^{24,25}, where the patterns were found to be localized near the electrodes and changed their direction upon reversal of the voltage polarity. Despite of similarities in their appearance, we assume that those patterns are flexodomains of another type with a different, not yet fully explored formation mechanism, where surface effects (e.g. anchoring and ion blocking strength, surface polarization, large electric field gradients near Debye layers) as well as differences in material parameters (ion concentration, elastic constants, etc.) may play an important role.

In Sec. 1 we already pointed out the advantages of using flexodomains in determining e^* , as well as the main drawback of this technique: only a few compounds possess the combination of the material parameters required for the appearance of flexodomains¹⁸. For example, in compounds with large positive dielectric anisotropy, FDs cannot be seen because their threshold voltage would be larger than that of the electric Freedericksz transition. However, we showed that applying a magnetic field in the perpendicular geometry substantially decreases $U_{c\perp}$, while the electric Freedericksz threshold remains unaffected by $B_{\perp} < B_t$. Therefore, our results opens a perspective to enlarge the number of nematics that may show FDs. Namely, we think that the application of a proper B_{\perp} will allow to observe FDs in compounds where no flexoelectric pattern formation can be seen in the absence of a magnetic field. Proving this will be the subject of further studies.

ACKNOWLEDGEMENTS

Financial support by the Hungarian Research Fund OTKA K81250 and the DAAD/MÖB researcher exchange program (grant no. 29480) are gratefully acknowledged.

References

- 1 P. G. de Gennes and J. Prost, *The Physics of Liquid Crystals*, 2nd ed., Clarendon Press, Oxford, (1993).
- 2 L. M. Blinov and V. G. Chigrinov, *Electrooptic Effects in Liquid Crystal Materials*, Springer, New York (1996).
- 3 R. Stannarius, In *Handbook of Liquid Crystals*, Eds. J. W. Goodby, P. J. Collings, T. Kato, C. Tschierske, H. Gleeson, P. Raynes, Wiley-VCH, Weinheim, Vol. 3, pp. 131 (2014).
- 4 R. B. Meyer, Piezoelectric effects in liquid crystals, *Phys. Rev. Lett.*, **22**, 918–921 (1969).
- 5 Á. Buka and N. Éber (eds.), *Flexoelectricity in Liquid*

- Crystals. Theory, Experiments and Applications, Imperial College Press, London, (2012).
- 6 J. Harden, B. Mbanga, N. Éber, K. Fodor-Csorba, S. Sprunt, J.T. Gleeson, and A. Jákli, *Phys. Rev. Lett.*, **97**, 157802 (2006).
 - 7 J. Harden, R. Teeling, J.T. Gleeson, S. Sprunt, and A. Jákli, *Phys. Rev. E*, **78**, 031702 (2008).
 - 8 P. Sathyanarayana, S. Radhika, B. K. Sadashiva, and S. Dhara, *Soft Matter*, **8**, 2322 (2012).
 - 9 W. Weissflog, U. Baumeister, M-G. Tamba, G. Pelzl, H. Kresse, R. Friedemann, G. Hempel, R. Kurz, M. Roos, K. Merzweiler, A. Jákli, C. Zhang, N. Diorio, R. Stannarius, A. Eremin, and U. Kornek, *Soft Matter*, **8**, 2671 (2012).
 - 10 A. Eremin and A. Jákli, *Soft Matter*, **9**, 615 (2013).
 - 11 N. Avci, V. Borshch, D. D. Sarkar, R. Deb, G. Venkatesh, T. Turiv, S. V. Shiyankovskii, N. V. S. Rao, and Oleg D. Lavrentovich, *Soft Matter*, **9**, 1066 (2013).
 - 12 S. Chakraborty, J. T. Gleeson, A. Jákli, and S. Sprunt, *Soft Matter*, **9**, 1817 (2013).
 - 13 F. Vita, I. F. Placentino, C. Ferrero, G. Singh, E. T. Samulski, and O. Francescangeli *Soft Matter*, **9**, 6475 (2013).
 - 14 J-H. Lee, T-H. Yoon, and E-J. Choi, *Soft Matter*, **8**, 2370 (2012).
 - 15 Eds. Á. Buka and L. Kramer, *Pattern Formation in Liquid Crystals*, Springer, New York (1996).
 - 16 Yu. P. Bobylev and S. A. Pikin, *Zh. Eksp. Teor. Fiz.* **72**, 369 (1977) [*Sov. Phys. JETP*, **45**, 195–198 (1977)].
 - 17 M. I. Barnik, L. M. Blinov, A. N. Trufanov, and B. A. Umanski, *J. Phys (Paris)*, **39**, 417 (1978)
 - 18 A. Krekhov, W. Pesch, and Á. Buka, *Phys. Rev. E*, **83**, 051706 (2011).
 - 19 G. Derfel and M. Buczkowska, *Mol. Cryst. Liq. Cryst.*, **547**, 213, (2011).
 - 20 F. Lonberg and R. B. Meyer, *Phys. Rev. Lett.* **55**, 718 (1985).
 - 21 P. Tadapatri and K. S. Krishnamurthy *J. Phys. Chem. B*, **116**, 782 (2012).
 - 22 P. Tadapatri, K. S. Krishnamurthy and W. Weissflog *Soft Matter*, **8**, 1202 (2012).
 - 23 B. A. Umanski, V. G. Chigrinov, L. M. Blinov, and Yu. B. Podyachev, *Zh. Eksp. Teor. Fiz.* **81**, 1307 (1981) [*Sov. Phys. JETP*, **54**, 694 (1981)].
 - 24 K. S. Krishnamurthy, P. Kumar and M. V. Kumar *Phys. Rev. E*, **87**, 022504 (2013).
 - 25 O. A. Elamain, *Bent Core Nematics, Alignment and Electro-Optic Effects*, Ph. D. thesis, University of Gothenburg (2013).
 - 26 K. S. Krishnamurthy, P. Kumar and P. Tadapatri *Journal of the Indian Institute of Science*, **89**, 255 (2009).
 - 27 S. L. Cornford, T. S. Taphouse, and J. R. Sambles *New J. Phys.* **11**, 013045 (2009).
 - 28 G. Derfel, *J. Mol. Liq.*, **144**, 59–64 (2009).
 - 29 F. C. M. Freire, G. Barbero, and M. Scalerandi *Phys. Rev. E*, **73**, 051202 (2006).
 - 30 F. C. Freire, A. L. Alexe-Ionescu, M. Scalerandi, and G. Barbero *Appl. Phys. Lett.*, **89**, 214101 (2006).
 - 31 G. Barbero, A. M. Figueiredo Neto, F. C. M. Freire, and J. Le Digabel *Phys. Rev. E*, **74**, 052701 (2006).
 - 32 G. Barbero, G. Cipparrone, O. G. Martins, P. Pagliusi, and A. M. Figueiredo Neto *Appl. Phys. Lett.*, **89**, 132901 (2006).
 - 33 A. L. Alexe-Ionescu, G. Barbero, and I. Lelidis *Phys. Rev. E*, **80**, 061203 (2009).
 - 34 L.O. Palomares, J.A. Reyes, and G. Barbero *Phys. Lett. A*, **333**, 157-163 (2004).
 - 35 R. Atasei, A.L. Alexe-Ionescu, J.C. Dias, L.R. Evangelista, and G. Barbero *Chem. Phys. Lett.*, **461**, 164169 (2008).
 - 36 G. Barbero, F. Batalioto, and A. M. Figueiredo Neto *Appl. Phys. Lett.*, **92**, 172908 (2008).
 - 37 P. Salamon, N. Éber, A. Krekhov and Á. Buka, *Phys. Rev. E*, **87**, 032505 (2013).
 - 38 E. Kochowska, S. Németh, G. Pelzl and Á. Buka, *Phys. Rev. E*, **70**, 011711 (2004).
 - 39 G. G. Nair, C. A. Bailey, S. Taushanoff, K. Fodor-Csorba, A. Vajda, Z. Varga, A. Bóta and A. Jákli, *Adv. Mater.*, **20**, 3138 (2008).
 - 40 P. Salamon, N. Éber, Á. Buka, J. T. Gleeson and S. Sprunt, A. Jákli, *Phys. Rev. E*, **81**, 031711 (2010).
 - 41 S. Rasenat, G. Hartung, B. L. Winkler and I. Rehberg, *Exp. Fluid*, **7**, 412 (1989).
 - 42 I. Stewart, *The Static and Dynamic Continuum Theory of Liquid Crystals*. Taylor & Francis, New York, 2004.
 - 43 N. Éber, L. O. Palomares, P. Salamon, A. Krekhov and Á. Buka, *Phys. Rev. E*, **86**, 021702 (2012).
 - 44 H. J. Deuling, E. Guyon, and P. Pieranski, *Solid State Commun.*, **15**, 277 (1974).

Flexoelectric patterns were studied under the influence of magnetic fields applied in different geometries in a nematic fluid.

